

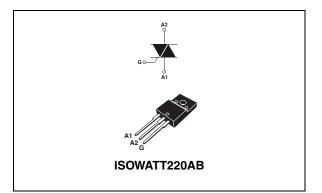
### Snubberless<sup>™</sup> 16A Triacs

### Features

- I<sub>T(RMS)</sub> = 16 A
- $V_{DRM} / V_{RRM} = 600, 700 \text{ and } 800 \text{ V}$
- I<sub>GT</sub> = 20 to 30 mA

### Description

Based on ST's Snubberless technology providing high commutation performances, the T1620-600W/700W/800W and T1630-600W are especially recommended for use with inductive loads such as rice cookers. They comply with UL standards (ref. E81734).



TM: Snubberless is a trademark of STMicroelectronics

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## 1 Characteristics

Table 1.	Absolute maximum ratings
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Symbol	Parameter		Value	Unit	
I <sub>T(RMS)</sub>	On-state rms current (full sine wave) $T_c = 80 \ ^{\circ}C$			16	А
	Non repetitive surge peak on-state current (full	F = 50 Hz	t = 20 ms	200	А
I <sub>TSM</sub>	cycle, T <sub>j</sub> initial = 25 °C)	F = 60 Hz	t = 16.7 ms	218	A
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		220	A <sup>2</sup> s
dl/dt	$ \begin{array}{ c c } \hline Critical rate of rise of on-state current I_G = 2 \ x \ I_{GT} \ , \ t_r \\ \leq 100 \ ns \end{array} \begin{array}{ c } F = 120 \ Hz \end{array} T  $		T <sub>j</sub> = 125 °C	50	A/µs
V <sub>DSM</sub> /V RSM	Non repetitive surge peak off-state voltage $t_p = 10 \text{ ms}$		T <sub>j</sub> = 25 °C	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V
I <sub>GM</sub>	Peak gate current $t_p = 20 \ \mu s$ $T_j = 125 \ ^{\circ}C$		4	А	
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 125 \text{ °C}$				W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range	- 40 to + 150 - 40 to + 125	°C		

### Table 2.Electrical characteristics (T<sub>j</sub> = 25 °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value		Unit
				T1620	T1630	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_{\rm D} = 12  \text{V}  \text{R}_{\rm I} = 30  \Omega$	-    -	MAX.	20	30	mA
V <sub>GT</sub>	$v_{\rm D} = 12 v_{\rm HL} = 30.22$	I - II - III MAX.		1.3		V
V <sub>GD</sub>	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 125 \text{ °C}$ I - II - III		MIN.	0.2		V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 250 mA	• •	MAX.	35	50	mA
	1 _ 1 2	I - III MAX.	80	m 4		
ΙL	I <sub>G</sub> = 1.2 I <sub>GT</sub> II		WAA.	80	100	mA
dV/dt <sup>(2)</sup>	$V_D = 67\% V_{DRM,}$ gate open, $T_j = 125 \text{ °C}$		MIN.	300	500	V/µs
(dl/dt)c (2)	Without snubber, T <sub>j</sub> = 125 °C	MIN.	8.5	11	A/ms	

1. minimum  $I_{GT}$  is guaranted at 5% of  $I_{GT}$  max.

2. for both polarities of A2 referenced to A1.



### Table 3.Static characteristics

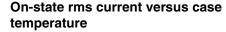
Symbol	Test conditions			Value	Unit
V <sub>T</sub> <sup>(1)</sup>	I <sub>TM</sub> = 22.5 A, t <sub>p</sub> = 380 μs	T <sub>i</sub> = 25 °C	MAX.	1.4	V
V <sub>TO</sub> <sup>(1)</sup>	Threshold voltage	T <sub>j</sub> = 125 °C	MAX.	0.85	V
$R_{D}^{(1)}$	Dynamic resistance	T <sub>j</sub> = 125 °C	MAX.	250	mΩ
I <sub>DRM</sub> I <sub>RRM</sub> V <sub>DRM</sub> = V <sub>RRM</sub>	V. – V.	T <sub>j</sub> = 25 °C	MAX.	5	μA
	VDRM = VRRM	T <sub>j</sub> = 125 °C		1	mA

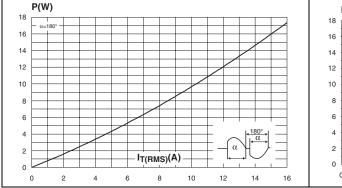
1. for both polarities of A2 referenced to A1.

### Table 4. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC) (360° conduction angle)	3.1	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	60	°C/W

# Figure 1. Maximum power dissipation versus Figure 2. on-state rms current





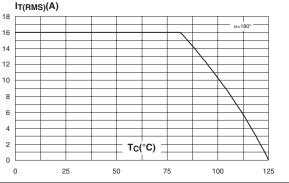
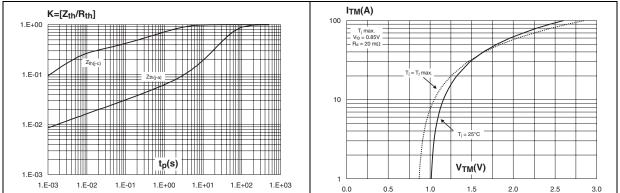
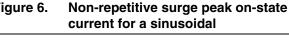


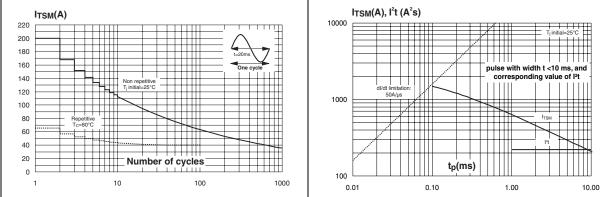
Figure 3. Relative variation of thermal impedance versus pulse duration

Figure 4. On-state characteristics (maximum values)



# Figure 5. Surge peak on-state current versus Figure 6. number of cycles





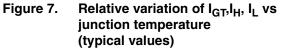


Figure 8. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)

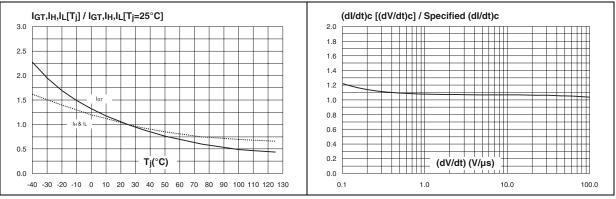
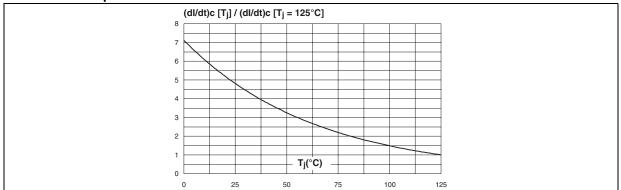


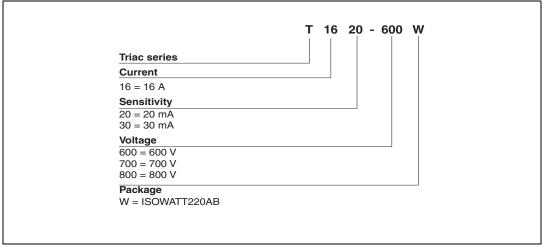
Figure 9. Relative variation of critical rate of decrease of main current versus junction temperature





## 2 Ordering information scheme

### Figure 10. Ordering information scheme



#### Table 5. Product Selector

Part Numbers	V	Voltage (xxx)		Sonoitivity	vity Type	Dookogo
Fait Numbers	600 V	700 V	800 V	Sensitivity	туре	Package
T1620-600W	Х					
T1620-700W		Х		20 mA		ISOWATT220AB
T1620-800W			Х	Shu	Snubberless	ISOWAI I 220AB
T1630-600W	Х			30 mA		



## 3 Package mechanical data

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. ISOWATT220AB dimensions

			Dimer	sions	
	Ref.	Millin	neters	Inc	hes
		Min.	Max.	Min.	Max.
А	Α	4.40	4.60	0.173	0.181
H B	В	2.50	2.70	0.098	0.106
	D	2.50	2.75	0.098	0.108
Dia	E	0.40	0.70	0.016	0.028
	F	0.75	1.00	0.030	0.039
L2 L7	F1	1.15	1.70	0.045	0.067
	F2	1.15	1.70	0.045	0.067
	G	4.95	5.20	0.195	0.205
	G1	2.40	2.70	0.094	0.106
	Н	10.00	10.40	0.394	0.409
	L2	16.00	) typ.	0.630	) typ.
	L3	28.60	30.60	1.125	1.205
G	L4	9.80	10.60	0.386	0.417
	L6	15.90	16.40	0.626	0.646
	L7	9.00	9.30	0.354	0.366
	Diam	3.00	3.20	0.118	0.126



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## 4 Ordering Information

### Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T1620-600W	T1620600W				
T1620-700W	T1620700W	ISOWATT220AB 2.	0 0 a	50	Tubo
T1620-800W	T1620800W	130WAI 1220AB	2.3 g	50	Tube
T1630-600W	T1630600W				

## 5 Revision history

Table 8.	Document revision history
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Date	Revision	Changes
Mar-2004	2	Last update.
18-Oct-2011	3	Insert T1620-700W, Insert 700 V in fig.10,deleted T1630-800W.



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